Attorney Docket: 361007-000036

10/685041

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Herr, Daniel Joseph Christian

Serial Number: Not Assigned Filed: Concurrently Herewith

For: SUPERMOLECULAR STRUCTURES AND DEVICES MADE FROM SAME

Commissioner for Patents PO Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. § 1.56 AND 37 C.F.R. § 1.97

It is respectfully requested that the document listed on the attached Form PTO/SB/08A be considered by the Patent and Trademark Office in the above-referenced application and made of record therein. A full text copy of the relevant documents have been previously disclosed in the parent application Ser. No. 09/510,802. This information disclosure statement submitted herewith is being filed within three months of the filing date of the application or date of entry into the national stage of an international application or before the mailing date of a first Office action on the merits, whichever event occurs last.

Respectfully submitted,

By:

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Registration No. 37,911
Attorney for Applicant
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2200 West Main Street, Suite 800

Durham, NC 27705 Phone: 919-286-8000 Facsimile: 919-286-8199 October 13, 2003

Date

PTO/SB/08A (08-00)

Approved for use through 10/31/2002. OMB 0851-0031
U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

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Substitute	for form 1449A/PTO			С	Complete if Known		
Į.				Application Number	09/510,802		
I	INFORMATION DISC	CLOS	URE	Filing Date	February 23, 2000		
	STATEMENT BY AP			First Named Inventor	Herr		
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Sheet	1	of	1	Attorney Docket Number	361007-0000007		
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		OTHER PRIOR ART—NON PATENT LITERATURE DOCUMENTS	
Examiner Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T2
	AA	D. M. Eigler et al., "Positioning single atoms with a scanning tunnelling microscope", Nature, Vol. 344 (April 1990) pp 524-526	
	AB	P. Bedrossian et al., "Demonstration of the tunnel-diode effect on an atomic", scale, <i>Nature</i> , Vol. 342 (November 1989) pp 258-260	

Examiner	Date
	Considered
Signature	

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

1 Unique citation designation number. 2See attached Kinds of U.S. Patent Documents. 3 Enter Office that issued the document, by the two-letter code (WIPO Standard St.3). 4For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. 5Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. 6Applicant is to place a check mark here if English language Translation is attached.

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				Application Number	09/510,802		
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	STATEMENT BY APP	LICA	\NT	First Named Inventor	Herr, Daniel Joseph Christian		
				Group Art Unit	2815		
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Sheet	1	of	2	Attorney Docket Number	361007-07		

				U.S. PATENT DOCUM	MENTS	
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Substitute	for form 1449B/PTO			Complete if Known			
				Application Number	#9/910,602		
1	INFORMATION DISCL	LOS	URE	Filing Date	February 23, 2000		
l	STATEMENT BY APP	LIC	ANT	First Named Inventor	Herr, Daniel Joseph Christian		
i				Group Art Unit	2815		
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Sheet	2	of	2	Attorney Docket Number	361007-000007		

		OTHER PRIOR ART—NON PATENT LITERATURE DOCUMENTS	
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